INTEGRATED CIRCUITS

DATA SHEET

74F253Dual 4-bit input multiplexer (3-State)

Product specification

1988 Nov 29

IC15 Data Handbook





74F253

FEATURES

- 3-State outputs for bus interface and multiplex expansion
- Common select inputs
- Separate Output Enable Inputs

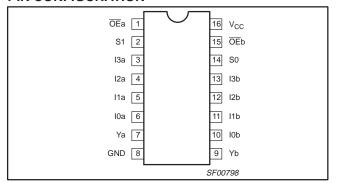
DESCRIPTION

The 74F253 has two identical 4-input multiplexers with 3-State outputs which select two bits from four sources selected by common Select inputs (S0, S1). When the individual Output Enable (OEa, OEb) inputs of the 4-input multiplexers are High, the outputs are forced to a high impedance (Hi-Z) state.

The 74F253 is the logic implementation of a 2-pole, 4-position switch; the position of the switch being determined by the logic levels supplied to the two common Select inputs.

To avoid exceeding the maximum current ratings when the outputs of the 3-State devices are tied together, all but one device must be in the high-impedance state. Therefore, only one Output Enable must be active at a time.

PIN CONFIGURATION



	TYPE	TYPICAL PROPAGATION DELAY	TYPICAL SUPPLY CURRENT (TOTAL)
ſ	74F253	7.0ns	12mA

ORDERING INFORMATION

	COMMERCIAL RANGE		
DESCRIPTION	V_{CC} = 5V ±10%, T_{amb} = 0°C to +70°C	PKG DWG #	
16-pin plastic DIP	N74F253N	SOT38-4	
16-pin plastic SO	N74F253D	SOT109-1	

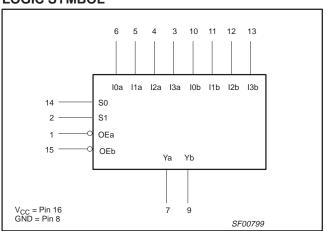
INPUT AND OUTPUT LOADING AND FAN-OUT TABLE

PINS	DESCRIPTION	74F (U.L.) HIGH/LOW	LOAD VALUE HIGH/LOW		
I0a–I3a	Port A data inputs	1.0/1.0	20μA/0.6mA		
I0b–I3b	Port B data inputs	1.0/1.0	20μA/0.6mA		
S0, S1	Common Select inputs	1.0/1.0	20μA/0.6mA		
OE a	Port A Output Enable input (active Low)	1.0/1.0	20μA/0.6mA		
OE b	Port B Output Enable input (active Low)	1.0/1.0	20μA/0.6mA		
Ya, Yb	3-State outputs	150/40	3mA/24mA		

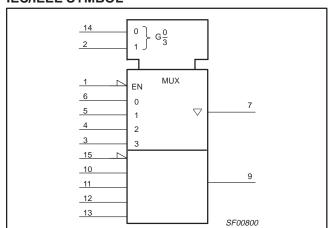
NOTE:

One (1.0) FAST unit load is defined as: $20\mu A$ in the High state and 0.6mA in the Low state.

LOGIC SYMBOL

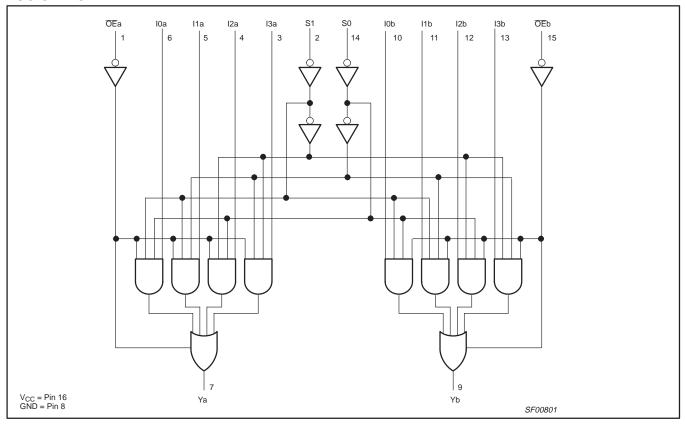


IEC/IEEE SYMBOL



74F253

LOGIC DIAGRAM



FUNCTION TABLE

	INPUTS											
S0	S1	10	I1	12	13	ŌĒ	Υ					
Х	Х	Х	Х	Х	Х	Н	Z					
L	L	L	Х	Х	Х	L	L					
L	L	Н	Х	Х	Х	L	Н					
Н	L	Х	L	Х	Х	L	L					
Н	L	Х	Н	Х	Х	L	Н					
L	Н	Х	Х	L	Х	L	L					
L	Н	Х	Х	Н	Х	L	Н					
Н	Н	Х	Х	Х	L	L	L					
Н	Н	Х	Х	Х	Н	L	Н					

NOTES:

H = High voltage level
L = Low voltage level
X = Don't care
Z = High impedance "off" state

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ABSOLUTE MAXIMUM RATINGS

(Operation beyond the limit set forth in this table may impair the useful life of the device. Unless otherwise noted these limits are over the operating free air temperature range.)

SYMBOL	PARAMETER	RATING	UNIT
V _{CC}	Supply voltage	-0.5 to +7.0	V
V _{IN}	Input voltage	-0.5 to +7.0	V
I _{IN}	Input current	−30 to +5	mA
V _{OUT}	Voltage applied to output in High output state	–0.5 to V _{CC}	V
I _{OUT}	Current applied to output in Low output state	48	mA
T _{amb}	Operating free-air temperature range	0 to +70	°C
T _{stg}	Storage temperature	-65 to +150	°C

RECOMMENDED OPERATING CONDITIONS

SYMBOL	DADAMETED		UNIT			
STWIBUL	PARAMETER	MIN	NOM	MAX	UNII	
V _{CC}	Supply voltage	4.5	5.0	5.5	V	
V _{IH}	High-level input voltage	2.0			V	
V _{IL}	Low-level input voltage			0.8	V	
I _{IK}	Input clamp current			-18	mA	
I _{OH}	High-level output current			-3	mA	
I _{OL}	Low-level output current			24	mA	
T _{amb}	Operating free-air temperature range	0		70	°C	

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DC ELECTRICAL CHARACTERISTICS

(Over recommended operating free-air temperature range unless otherwise noted.)

SYMBOL	PARAMETE	₹	TEST COND	MIN	TYP NO TAG	MAX	UNIT		
V	I limb lavel autout valta es		V _{CC} = MIN, V _{IL} = MAX,	Vcc = MIN. VII = MAX. ±10%Vc					V
V _{OH}	High-level output voltage	High-level output voltage			±5%V _{CC}	2.7	3.3		V
			V _{CC} = MIN, V _{IL} = MAX,		±10%V _{CC}		0.35	0.50	V
V _{OL}	Low-level output voltage		V _{IH} = MIN, I _{OL} = MAX		±5%V _{CC}		0.35	0.50	V
V _{IK}	Input clamp voltage		$V_{CC} = MIN, I_I = I_{IK}$				-0.73	-1.2	V
I _I	Input current at maximur voltage	n input	$V_{CC} = MAX, V_I = 7.0V$					100	μΑ
I _{IH}	High-level input current		$V_{CC} = MAX, V_I = 2.7V$	$V_{CC} = MAX, V_I = 2.7V$				20	μΑ
I _{IL}	Low-level input current		$V_{CC} = MAX, V_I = 0.5V$					-0.6	mA
I _{OZH}	Off-state output current High-level voltage applie	ed	$V_{CC} = MAX, V_O = 2.7V$					50	μА
I _{OZL}	Off-state output current Low-level voltage applie	d	$V_{CC} = MAX, V_{O} = 0.5V$				-50	μА	
Ios	Short-circuit output curre	ent ^{NO TAG}	V _{CC} = MAX		-60		-150	mA	
		I _{CCH}	ŌEn=GN		Sn=In=4.5V		10	16	mA
I _{CC}	Supply current (total) ICCL ICCZ		$V_{CC} = MAX$ $\overline{OE}n=Sn=In=0$		DEn=Sn=In=GND		12	23	mA
				OEn=4.5V, Sn=		·	14	23	mA

NOTES:

1. For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions for the applicable type.

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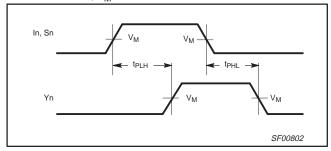
All typical values are at V_{CC} = 5V, T_{amb} = 25°C.
 Not more than one output should be shorted at a time. For testing I_{OS}, the use of high-speed test apparatus and/or sample-and-hold techniques are preferable in order to minimize internal heating and more accurately reflect operational values. Otherwise, prolonged shorting of a High output may raise the chip temperature well above normal and thereby cause invalid readings in other parameter tests. In any sequence of parameter tests, I_{OS} tests should be performed last.

AC ELECTRICAL CHARACTERISTICS

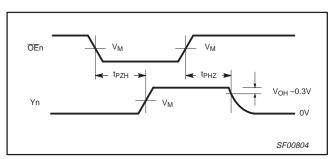
SYMBOL	PARAMETER	TEST CONDITION		V _{CC} = +5V _{amb} = +25° C _L = 50pF R _L = 500Ω	'	V _{CC} = +5 T _{amb} = 0°C C _L = R _L = 5	UNIT	
			MIN	TYP	MAX	MIN	MAX	
t _{PLH} t _{PHL}	Propagation delay In to Yn	Waveform NO TAG	3.0 3.0	4.5 5.0	7.0 7.0	3.0 3.0	7.5 8.0	ns
t _{PLH} t _{PHL}	Propagation delay Sn to Yn	Waveform NO TAG	4.5 5.0	7.5 8.5	10.5 11.0	4.5 4.5	11.0 12.0	ns
t _{PZH}	Output Enable time to High or Low level	Waveform 2 Waveform 3	3.0 3.0	6.5 6.5	8.0 8.0	3.0 3.0	9.0 9.0	ns
t _{PHZ}			2.5 2.0	3.5 3.0	5.0 5.0	2.0 1.5	6.0 6.0	ns

AC WAVEFORMS

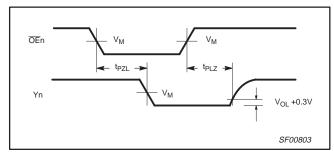
For all waveforms, $V_M = 1.5V$



Waveform 1. Propagation Deley, Data and Select to Output



Waveform 2. 3-State Output Enable Time to High Level and Output Disable Time from High Level



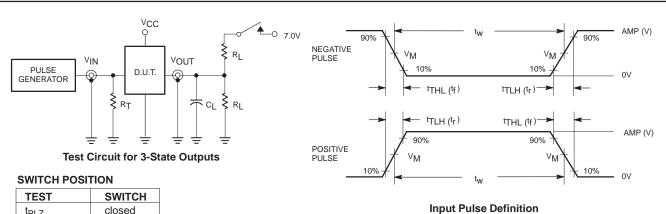
Waveform 3. 3-State Output Enable Time to Low Level and Output Disable Time from Low Level

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TEST CIRCUIT AND WAVEFORMS



TE	ST	SWITCH
t _{PL}	Z	closed
t _{PZ}	L	closed
All	other	open
		•

DEFINITIONS:

 R_L = Load resistor;

see AC electrical characteristics for value.
Load capacitance includes jig and probe capacitance; see AC electrical characteristics for value.

Termination resistance should be equal to $Z_{\mbox{\scriptsize OUT}}$ of pulse generators.

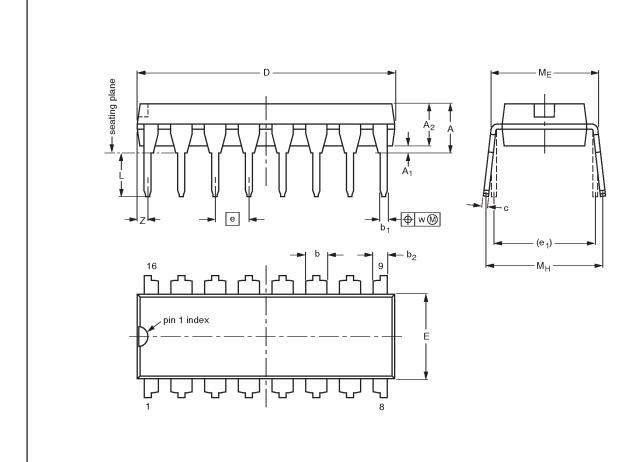
family	INP	UT PU	LSE REQU	REMEN	TS	
lallilly	amplitude	V_{M}	rep. rate	t _w	t _{TLH}	t _{THL}
74F	3.0V	1.5V	1MHz	500ns	2.5ns	2.5ns

SF00777

74F253

DIP16: plastic dual in-line package; 16 leads (300 mil)

SOT38-4



DIMENSIONS (inch dimensions are derived from the original mm dimensions)

UNIT	A max.	A ₁ min.	A ₂ max.	b	b ₁	b ₂	O	D ⁽¹⁾	E ⁽¹⁾	е	e ₁	L	ME	Мн	w	Z ⁽¹⁾ max.
mm	4.2	0.51	3.2	1.73 1.30	0.53 0.38	1.25 0.85	0.36 0.23	19.50 18.55	6.48 6.20	2.54	7.62	3.60 3.05	8.25 7.80	10.0 8.3	0.254	0.76
inches	0.17	0.020	0.13	0.068 0.051	0.021 0.015	0.049 0.033	0.014 0.009	0.77 0.73	0.26 0.24	0.10	0.30	0.14 0.12	0.32 0.31	0.39 0.33	0.01	0.030

10 mm

Note

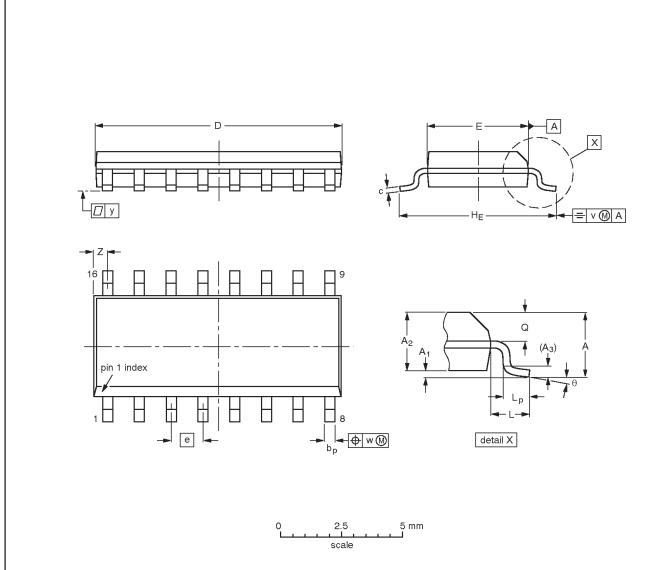
1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE			
VERSION	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE	
SOT38-4						92-11-17 95-01-14	

74F253

SO16: plastic small outline package; 16 leads; body width 3.9 mm

SOT109-1



DIMENSIONS (inch dimensions are derived from the original mm dimensions)

UNIT	A max.	A ₁	A ₂	A ₃	bp	c	D ⁽¹⁾	E ⁽¹⁾	е	HE	L	Lp	Q	v	w	у	Z ⁽¹⁾	θ
mm	1.75	0.25 0.10	1.45 1.25	0.25	0.49 0.36	0.25 0.19	10.0 9.8	4.0 3.8	1.27	6.2 5.8	1.05	1.0 0.4	0.7 0.6	0.25	0.25	0.1	0.7 0.3	8°
inches	0.069	0.010 0.004	0.057 0.049	0.01		0.0100 0.0075	0.39 0.38	0.16 0.15	0.050	0.244 0.228	0.041	0.039 0.016		0.01	0.01	0.004	0.028 0.012	0°

Note

1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.

OUTLINE		REFER	RENCES	EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	EIAJ	PROJECTION	1330E DATE
SOT109-1	076E07S	MS-012AC			-95-01-23- 97-05-22

74F253

Data sheet status

Data sheet status	Product status	Definition [1]
Objective specification	Development	This data sheet contains the design target or goal specifications for product development. Specification may change in any manner without notice.
Preliminary specification	Qualification	This data sheet contains preliminary data, and supplementary data will be published at a later date. Philips Semiconductors reserves the right to make chages at any time without notice in order to improve design and supply the best possible product.
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^[1] Please consult the most recently issued datasheet before initiating or completing a design.

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